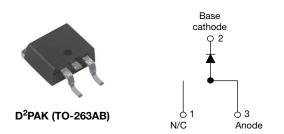
VS-18TQ035SPbF, VS-18TQ040SPbF, VS-18TQ045SPbF

Vishay Semiconductors

High Performance Schottky Rectifier, 18 A



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SHA

PRIMARY CHARACTERISTICS					
I _{F(AV)}	18 A				
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.53 V				
I _{RM}	25 mA at 125 °C				
T _J max.	175 °C				
E _{AS}	24 mJ				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 ALOGEN
 FREE



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-18TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS	AND CHARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	18	A
V _{RRM}	Range	35 to 45	V
I _{FSM}	t _p = 5 μs sine	1800	A
V _F	18 A _{pk} , T _J = 125 °C	0.53	V
TJ	Range	-55 to +175	°C

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-18TQ035SPbF	VS-18TQ040SPbF	VS-18TQ045SPbF	UNITS
Maximum DC reverse voltage	V _R	35	40	45	V
Maximum working peak reverse voltage	V _{RWM}		40	40	v

ABSOLUTE MAXIMUM RATI	NGS				
PARAMETER	SYMBOL	TEST CONDIT	TIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 149 °C	c, rectangular waveform	18	А
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	1800	
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	390	A
Non-repetitive avalanche energy	E _{AS}	$T_{J} = 25 \ ^{\circ}C, I_{AS} = 3.6 \ A, L = 3.7$	mH	24	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxim	ro in 1 μs um V _A = 1.5 x V _R typical	3.6	А

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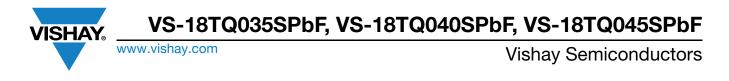
ELECTRICAL SPECIFICAT	ONS				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		18 A	T.I = 25 °C	0.60	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	36 A	1j=25 C	0.72	V
See fig. 1	VFM ()	18 A	T.I = 125 °C	0.53	v
		36 A	1j = 125 C	0.67	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2.5	mA
See fig. 2	IRM ("	T _J = 125 °C	V _R = naleu V _R	25	ША
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz), 25 °C	1400	pF
Typical series inductance	Ls	Measured lead to lead 5	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

ISHAY

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECI	HANICAL	SPECIFIC	ATIONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	je	T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resista junction to case	ince,	R _{thJC}	DC operation See fig. 4	1.50	°C/W
Typical thermal resistanc case to heatsink	e,	R _{thCS}	Mounting surface, smooth and greased	0.50	0/10
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
				18TQ	035S
Marking device			Case style D ² PAK (TO-263AB)	18TQ	040S
				18TQ	045S



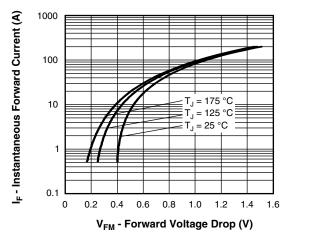
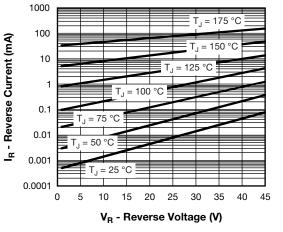
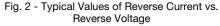


Fig. 1 - Maximum Forward Voltage Drop Characteristics





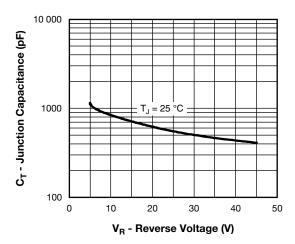
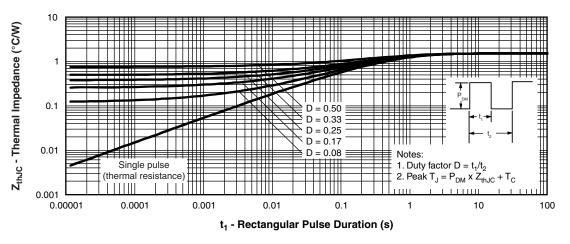


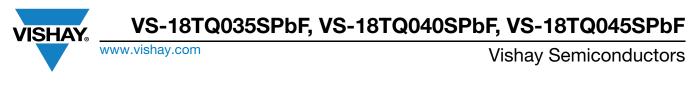
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

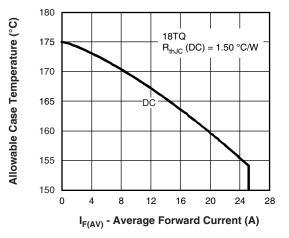


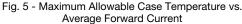


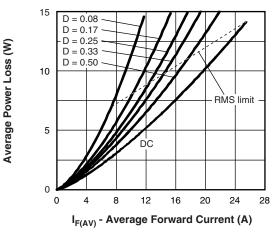
 Revision: 04-Aug-17
 3
 Document Number: 94150

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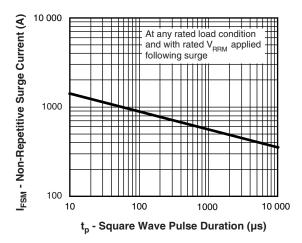














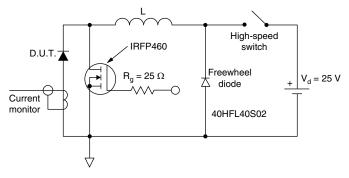


Fig. 8 - Unclamped Inductive Test Circuit

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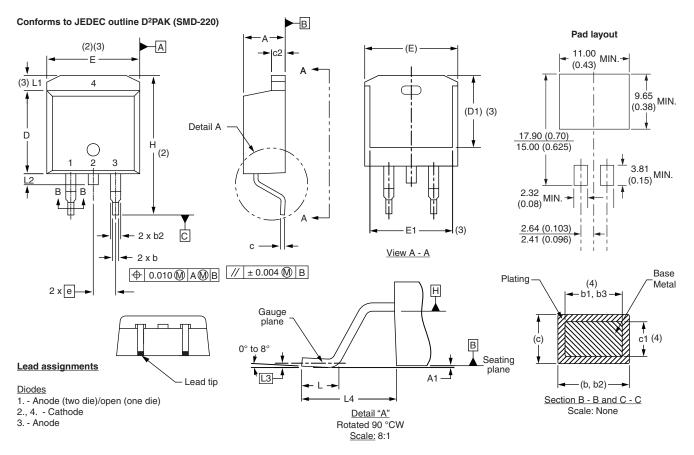
ORDERING INFORMATION TABLE

Device code	VS-	18	т	Q	045	S	TRL	PbF
	1	2	3	4	5	6	7	8
	1 - 2 - 3 - 4 - 5 -	- Cur - Circ - Sch	rent rati cuit cont	niconduo ng (18 A figuratio Q" series ngs —	•) n: T = T	O-220	35 = 35 40 = 40	V
	6 - 7 -			(TO-263 ibe (50 p	,		45 = 45	
				be and re	`		,	
	8 -			be and r (Pb)-fre		it orient	eu)	

LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?96209

Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09

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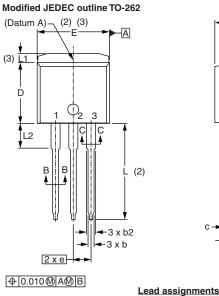
Outline Dimensions

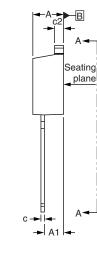
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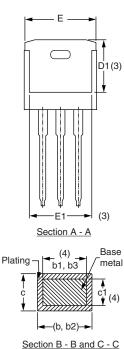
D²PAK, TO-262



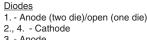
DIMENSIONS - TO-262 in millimeters and inches

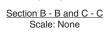






Lead tip





SYMBOL	MILLIN	METERS	INCI	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

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actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



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